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Review article

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The current state of the art in internal additive materials and quantum dots for improving efficiency and stability against humidity in perovskite solar cells

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HIGHLIGHTS

- Surface passivation, polymer-mixed perovskite, and quantum dots (QDs) as strategies to enhance stability have been reviewed.
- QDs implemented in perovskite sheets, HTLs, and ETLs demonstrate improvements in the efficiency of perovskite solar cells.
- The implementation of QDs results in the reduction of recombination pathways, resulting in the long-term stability of devices.

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G R A P H I C A L A B S T R A C T



ABSTRACT

The remarkable optoelectronic capabilities of perovskite structures enable the achievement of astonishingly highpower conversion efficiencies on the laboratory scale. However, a critical bottleneck of perovskite solar cells is their sensitivity to the surrounding humid environment affecting drastically their long-term stability. Internal additive materials together with surface passivation, polymer-mixed perovskite, and quantum dots, have been investigated as possible strategies to enhance device stability even in unfavorable conditions. Quantum dots (QDs) in perovskite solar cells enable power conversion efficiencies to approach 20%, making such solar cells competitive to silicon-based ones. This mini-review summarized the role of such QDs in the perovskite layer, hole-

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1. Perovskite solar cells and their states of stability

Photovoltaic (PV) devices, which are frequently called solar cells, harvest sunlight and convert it directly to electricity (as a renewable energy technology). For many years, silicon-based solar cells represent the industrial dominant standard technology in PVs. Such commercial technologies have historically been defined by their high performance, low cost, and stability. However, solar cells based on silicon are intrinsically compromised by high energy and material demand during production, and several difficulties with their end-of-life management, such as high costs to delaminate silicon wafers from the glass substrate or to recovery high-grade silicon (from mixed output materials after mechanical separation) by metallurgical processes [1, 2]. Emerging photovoltaics are on their way from lab-scale to industrial production [3]. Several researchers have identified perovskite solar cells, also named hybrid organic-inorganic perovskite solar cells, as particularly promising PV technologies alternatives [4, 5, 6]. These technologies not only demonstrate a high efficiency comparable to silicon-based solar cells, but also novel fields of application, as perovskite emerging photovoltaics can be designed of flexible, ultrathin, and light materials. Cost efficiency during the manufacturing processes can be improved by utilizing solution processes and simple fabrication methods at low temperature [7]. Thus, in comparison to silicon-based, energy, chemical, and material demand can be reduced by innovative (e.g., role-to-role) fabrication methods of perovskite solar cells [8]. Perovskite, a hybrid organic-inorganic material composed of halides with an ABX₃ crystal structure and polymeric substrates, is regarded as an ideal material for portable solar cell applications to deliver energy for off-grid solutions. Typically, perovskite cells are prepared by modifying one of two device configurations: the normal (n-i-p) or the inverted (p-i-n) configuration. Currently, the certified power conversion efficiency (PCE) of perovskite solar cells evolved from 3.8% in 2009 [4] to 25.5% in 2021 [9], but the long-term stability of the devices renders a significant barrier to successful commercialization [10]. An important technological leap in the development was made by the deposition of perovskite (CH₃NH₃PbI₂Cl) onto mesoporous Al_2O_3 and TiO_2 layers, which were contacted to 2,2',7, 7'-tetrakis(N,N-di-p-methoxyphenylamine)-9,9'-spirobifluorene (spiro-MeOTAD) as hole transport layer (HTL) [11]. In 2021, Chen et al. [12], reported that dimethyl sulfoxide (DMSO), a liquid additive typically applied to enhance perovskite film morphology, was trapped during film formation. This leads to void formation at the interfaces of perovskite and substrate, accelerating the degradation of the film under illumination. The elimination of voids in the structure can be achieved by the replacement of dimethyl sulfoxide with carbohydrazide. The obtained solar cells maintained high power conversion efficiency without efficiency loss of operation at 60 °C after 550 h. The validated PCEs of the perovskite mini-modules were 19.3% with an area of the aperture of 18.1 cm^{2} [12].

Such novel solar cell architectures with organic-inorganic perovskite as a light-harvesting absorber thus possess a high absorption coefficient, excellent charge carrier mobility for electron-hole pairs, readily tunable bandgap energy, and a variety of facile synthetic processes for cell fabrication [13, 14, 15]. The general crystal structure of perovskite is ABX₃, whereat A is an inorganic or organic cation that is larger than the metal cation B, and X represents the anion. The most frequently encountered hybrid perovskites are composed of methylammonium (CH₃NH₃⁺), lead (Pb²⁺), and a halide (I⁻, Br⁻, or Cl⁻) or a mixture of halides [16, 17]. Probably the biggest disadvantage of perovskites is their instability under ambient environmental conditions, as these materials are sensitive to light, oxygen, and moisture [18, 19]. One of these mechanisms is the photooxidation by the formation of superoxide free radicals (O^{2-}) that are generated, when ammonium iodide (CH_3NH_3I) is illuminated and decomposes to water (H_2O), iodide (I_2), and methylamine (CH_3NH_2), while solid phases of PbI₂ remain as a product, as shown in Eqs. (1) and (2), respectively [18, 19]. Another possible photooxidation mechanism is initiated by the donation of an electron from the iodide anion (I^-), to oxygen molecules, resulting in the generation of superoxide free radicals that can cause damage to the perovskite.

$$CH_3NH_3PbI_3 (s) + hv \rightarrow CH_3NH_3I + PbI_2$$
(1)

$$2CH_3NH_3I + 1/2O_2 \rightarrow H_2O + I_2 + 2CH_3NH_2$$
 (2)

Moisture also represents a significant impediment to the stability of perovskite solar cells. As shown in Eqs. (3), (4), and (5), moisture can trigger a different chemical reaction that leads to a structural change and consequently loss of photovoltaic efficiency [20, 21, 22]. Water molecules can degrade the perovskite structure of $CH_3NH_3PbI_3$ by the formation of octahedral lead iodide (PbI_6^4) and PbI_2 (Eq. (3)). Another possible interaction of water molecules with $CH_3NH_3PbI_3$ is its initial integration, by an intermediate monohydrate ($CH_3NH_3PbI_3\cdot H_2O$; Eq. (4)) that leads to degradation to CH_3NH_3I and PbI_2 with no phase separation (Eq. (5)).

$4CH_3NH_3PbI_3 + 2H_2O -$	$(CH_3NH_3)_4PbI_6 \cdot 2H_2O + 3PbI_2$	(3)
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$$CH_{3}NH_{3}PbI_{3} + H_{2}O \leftrightarrow CH_{3}NH_{3}PbI_{3} \cdot H_{2}O$$
(4)

 $CH_{3}NH_{3}PbI_{3}.H_{2}O \leftrightarrow CH_{3}NH_{3}I + PbI_{2} + H_{2}O$ (5)

It has been described [20, 21, 22] that lead iodide-based perovskite decomposes to PbI₂ when it is in contact with a polar solvent, such as water. There is still significant concern regarding the release of toxic lead into the environment, so lead-free perovskite composition must become the standard for environmentally friendly solar cell technologies [23]. Thus, strategies for preventing environmental factors, particularly moisture, reacting with perovskite materials in photovoltaic cells include (i) encapsulation of such devices as an external protection measure and (ii) passivation engineering as internal protection approach.

This review focuses on strategies for improving the stability and efficiency due to internal protection by using additives for material passivation, which includes surface perovskite films, large- and smallmolecule additives, and quantum dots (QDs) additives. By avoiding the decomposition of perovskite materials, the release of toxic materials such as Pb compounds can be reduced, which can turn perovskite-based cells into good candidates for the development of more sustainable solar cells. This work also discusses the fundamental theory and unique properties of QDs. Here we want also to highlight the various types of QDs (and their exceptional photonic properties) that can be integrated into the active layer, hole-transporting layer (HTL), and electron-transporting layer (ETL) of perovskite photovoltaic devices and could improve these technologies to become more sustainable and efficient.

2. Challenges in stabilizing perovskite solar cells

Uniform perovskite films degrade rapidly when they are subjected to environmental factors such as heat, moisture, light, and radiolysis. Moisture leads to structural defects, as perovskite is very hygroscopic [24]. UV light leads to photodegradation of the perovskite or TiO_2 layers. Oxidation and formation of large PbI₂ structures can also occur, especially at high temperatures and in humid environments [25]. Some research groups have investigated perovskite films with high moisture sensitivity by studying color-changing perovskite films in atmospheric moisture [26, 27, 28]. As previously addressed, moisture stability represents a major obstacle to the commercialization of perovskite solar cells. Perovskite films degrade rapidly in the presence of water and oxygen, where water molecules quickly form strong hydrogen bonds, which form hydroiodic acid (HI) [28]. Imperfections, such as bulk flaws, grain boundaries, surface flaws, and interface flaws are usually the places where the degradation is initiated [29, 30]. Generally, preparation methods for metal halide perovskite films that are based on wet chemistry reduce the performance of the final solar cell device [30]. Defects in the perovskite solar cells have also an impact on the efficiency leading to voltage losses and weak charge transport, both of which are caused by the formation of undesirable non-radiative channels. Photo-generated charge carriers recombination occurs through such non-radiative channels, adversely affecting the efficiency of perovskite solar cells [29, 30]. As a result, it is essential to develop hydrophobic materials that can ideally prevent the diffusion of moisture to the perovskite, passivate defects, and promotes charge transport.

3. Improvement of humidity stability in perovskite solar cells

3.1. External encapsulation of perovskite solar cells

The simplest solution to prevent the diffusion of moisture into photovoltaic cells is a tight encapsulation. More common device encapsulation methods typically include the use of appropriately sized glass coverslips, which can be applied to the entire device based on rigid substrates [31], and can then be sealed with epoxy resin, surlyn, ethylene vinyl acetate (EVA) as well as polyolefin materials for the laboratory manufacturing process. When working in small production scales, this encapsulation technique might be acceptable but is currently impractical for larger-scale productions [7, 32, 33].

3.2. Modification of perovskite films by surface passivation

To protect the surface from moisture, one strategy is to incorporate a thin passivation layer. Incorporating a thin insulating contact layer between the perovskite/cathode sides resulted in a straightforward method of preventing water-induced damage. The ultra-thin insulating layer inserted into the perovskite film enables charge tunneling, which not only transfers electrons from the perovskite film to the HTL but also blocks holes at the interface, as illustrated in Figure 1a [34]. The insulating layer needs to be as thin as possible, but sufficiently thick to withstand moisture. The critical tunneling properties of the insulation layer have been discussed and summarized in previous review reports [35, 36]. As shown in Table 1, a variety of polymeric insulating materials and insulating oxides (such as Al_2O_3) were reported to improve moisture protection in perovskite solar cells.

The majority of these materials consist of alkyl chains, acids, and thiol groups. By coating on top of the perovskite surface, the hydrophilic nature of the perovskite film is altered, resulting in the formation of hydrophobic films. For example, Zhang et al. used amphiphilic dodecyl-trimethoxysilane (C_{12} -silane) as an insulating layer with an alkyl chain to passivate the perovskite/HTL interface (Figure 1b). They discovered that the hydrophobic alkyl chain layer created a more resistant perovskite surface, as the contact angle of perovskite with C_{12} -silane was increased from 44.1° to 86.3° in the reference films [37].

Following that, Xiong et al. reported that using 2%wt triethoxy-1H,1H,2H,2H-tridecafluoro-*n*-octylsilane-(C_{13} -FAS) as a fluoroalkyl silane for perovskite surface encapsulation reduced the device hysteresis and improved the stability in air at ca. 50% humidity [38]. The efficiency of perovskite solar cells covered by C_{13} -FAS through spin coating remained at 12% humidity for 500 h, when compared to a non-coated cell that was operated at 1% humidity for 250 h. Additionally, the contact angle as a measure for hydrophobicity of the unmodified perovskite surface was around 41.8°, whereas the C_{13} -FAS modified perovskite film

presented a maximum contact angle of 85.5° (Figure 1c). As a result, both C12-silane and C13-FAS contain a silanol (Si-OH) group that can be absorbed onto the perovskite surface via a hydrogen bond between the Si-OH and the perovskite iodide ion [38]. Zhu et al., found that surface modification of CH₃NH₃PbI₃ with 4-dimethylaminobenzoic acid (4-DMABA) increased the stability of the material up to 1000 h at 70% relative humidity and additionally the efficiency of perovskite photovoltaic applications from 17.43% to 19.87% [39]. The concept beyond 4-DMABA films is that its carboxyl group coordinates closely with lead (Pb²⁺) in perovskite crystals, while the hydrophobic properties of the ligand are effectively repelling water molecules. Figure 1d illustrates the interaction mode of 4-DMABA molecules with MAPbI₃ [39]. Cao et al., calculated the effect of covering perovskite films with pentafluorobenzenethiol (e.g., $HS-C_6F_5$) on the hydrophobic thiol molecule layer through the Pb-S bonding interaction [40]. Similarly, Abdelmageed et al., investigated the use of a spin coating to deposit oleic acid (OA) on top of perovskite layers, resulting in the formation of hydrophobic thin films through the interaction of the OA carboxyl group (COO^{-}) with the Pb²⁺ and/or CH₂NH³⁺ ion groups. This modification demonstrated that the sample could remain stable at 76% humidity for four weeks [41]. Another way to improve the stability of photovoltaic cells was to deposit Al₂O₃, which serves as a surface passivation layer between the perovskite/HTL interface, by atomic layer deposition, maintaining the efficiency of the cell for approximately 1680 h at 40-70% relative humidity, as measured by Koushik et al. [42].

Many research reports have continuously improved the stability of inverted perovskite solar cells against high humidity by using polymer additives in different layers of perovskite solar cells [43, 44, 45, 46, 47, 48]. Zhang et al. optimized HTL with polyphenylene sulfide as insulating additives, thereby increasing PCE from 19.1 to 21.5 % and achieving 574 h of device stability under aging conditions. The improvement is due to the larger grain sizes of perovskite film and optimized energy-level alignment at the interface between HTL/perovskite after the addition of polyphenylene sulfide, which suppresses the additive-induced decrease in conductivity [43]. Using polymer additives such as a fluorinated lead salt in a methylammonium lead iodide perovskite composition transforms the perovskite layer into the three-dimensional methylammonium lead iodide perovskite, allowing the fabrication of simple inverted solar cells at low temperatures [44]. Additionally, there are several polymer additives for using in the inverted structure like polyaniline-modified camphor sulfonic acid (PANI-CSA) in HTL [45], using a novel ionic silicone polymer in perovskite layer to chelate undercoordinated Pb^{2+} and Pb clusters to passivate deep defect [46] and also using the mixed polymer made of an indacenodithiophene and a thiadiazolequinoxaline (PIDTTDQ) replace PEDOT:PSS as a new hydrophobic HTL [47], and another by inducing amine-functionalized small molecules between ETL/electrode [48]. Thus, additive engineering is an effective strategy as a simple technique with enhanced solar cell stability of inverted perovskite solar cells.

In summary, a simple method to protect perovskite from moisture is to cover it with hydrophobic ultra-thin films on top of the perovskite surface by solution processes or vapor-deposition methods, as shown in the above-mentioned approaches. For such coatings, small organic molecules were shown to perform well, when they contained amphiphilic or hydrophobic groups. Several hydrophobic molecules can be employed to increase the stability of the nano-interfaces of perovskite surfaces in conditions of relative humidity ranging between 45% and 75%, which are summarized in Table 1.

3.3. Modifications of perovskite films by additive materials

3.3.1. Polymeric additives in perovskite precursors

Due to the high hygroscopicity of perovskite, additives with small and large molecules in perovskite precursors are regarded as a promising way to increase the stability of perovskite solar cells [22]. Figure 2 illustrates



Figure 1. a) The energy diagram illustrates the principle of suppressing surface charge recombination by the insulating layer strategy. The insulating layer of choice suppresses charge recombination by separating the excess electrons and holes in the electron transport layer and perovskite layer, respectively (reproduced with permission [34], copyright 2016, Wiley Online Library); b) The formation process of the mesoporous perovskite device with C_{12} -silane modification (reproduced with permission [37], copyright 2015, The Royal Society of Chemistry); c) The contact angle of unmodified and modified perovskite film of C_{13} -FAS (reproduced with permission [38], copyright 2016, The Royal Society of Chemistry); and d) Schematic diagram showing the interaction mode of 4-DMABA molecules with MAPbI₃ (reproduced with permission [39], copyright 2018, The Royal Society of Chemistry).

the chemical structures of various additive materials in perovskite solutions while Table 2 summarizes several known polymeric additives for perovskite modifications. The illumination of perovskite films in presence of oxygen leads to its degradation and to the formation of structural defects in the nanocrystals and in turn to a decrease of the PCE [49, 50]. According to the degradation mechanisms, superoxide (O_2) is formed when oxygen (O_2) reacts during UV exposure to perovskite films. When O_2 reacts with the perovskite surface, methylamine (CH₃NH₂), PbI₂, water, and I₂ are generated and thus inhibit the crystallization of the perovskite structure during particle growth or the deposition methods to fabricate the layers. Polymer-additives can inhibit the diffusion of O_2 and maintain the perovskite crystallization when they are added to a perovskite precursor solution.

Xiang et al. [51] synthesized poly(dimethylsiloxane)-urea (PDMS-urea), the co-block polymer, which was used to fabricate perovskite solar cells. They discovered that PDMS-urea significantly improved the stability of perovskite solar cells because a portion of the urea group could form tight hydrogen bonds with the perovskite while the poly(dimethylsiloxane) domains provided a flexible, hydrophobic chain that protected the light-absorber surface from moisture.

Passivation layer	Chemical structure (Molecular weight, MW)	Material property	Device stability/ humidity test	Contact angle of perovskite films	Ref.
4-dimethyl aminobenzoic acid	$(MW = 165.19 \text{ g mol}^{-1})$	Hydrophobic	1,000 h, 70 %RH	65.0° (with passivation layers) – 45.0° (without passivation layers)	[39]
Triethoxy- 1H,1H,2H,2H- tridecafluoro-n- octylsilane (C ₁₃ -FAS)	$(MW = 510.37 \text{ g mol}^{-1})$	Hydrophobic	500 h, ~50 %RH	85.5° (with passivation layers) – 41.8° (without passivation layers)	[38]
Dodecyl- trimethoxysilane (C ₁₂ -silane)	(MW = 290.52 g mol ⁻¹)	Amphiphilic	600 h, 45 %RH	86.3° (with passivation layers) – 44.1° (without passivation layers)	[37]
Pentafluorobenzen ethiol	F = F = F $F = F$	Hydrophobic	250 h, 45 %RH	-	[40]
Oleic acid (OA)	$(MW = 282.47 \text{ g mol}^{-1})$	Hydrophobic	672 h, ~76 %RH	- -	[41]
Aluminum oxide	$Al_2O_3 \ (MW = 101.96 \ g \ mol^{-1})$	Insoluble in water	1,680 h, 40-70 %RH	-	[42]

Table 1. Various passivation layers increase the humidity stability of perovskite absorbers.

Internal encapsulating perovskite solar cell devices with polymethyl methacrylate (PMMA) represents a standard procedure for increasing stability against humidity. The PMMA was used to enhance nucleation and improve the uniformity of the perovskite films with high charge transfer properties. A combination of perovskite and PMMA for surface passivation of the absorber layer demonstrated a certified PCE of over 21% from Bi et al. [52] Zhao et al. [53] recorded on a uniform perovskite film with a polyethylene glycol (PEG)-scaffold model with a PCE of 16%. After 300 h of aging at 70% relative humidity, the unencapsulated perovskite solar cell retained 65% of its PCE. In Figure 3a, a schematic diagram illustrating the fabrication process of a perovskite film with a PEG scaffold using a one-step spin coating method is shown, along with SEM images of the perovskite surface without and with PEG. This work demonstrated the self-healing properties of PEG-scaffold perovskite films due to the PEG molecules with high hygroscopicity, which can form hydrogen bonds with the methylammonium iodide (MAI) molecules in perovskite [53]. Sun et al. published the use of polyvinylidene fluoride trifluoroethylene P(VDF-TrFE) as an additive polymer in PbI₂ solution to boost the photovoltaic efficiency of devices through a two-step deposition process [54]. The addition of the polymer P(VDF-TrFE) raised the PCE from 9.90% to 13.24% due to the improved crystallinity and morphology of the perovskite films caused by adding P(VDF-TrFE). Another study by Li et al., demonstrated that surface passivation, which was induced by polyvinylpyrrolidone (PVP), could aid the cubic phase formation of CsPbI₃ crystal structure and thus improving the long carrier diffusion length of perovskite. PVP was shown to adsorb physically onto the surface of CsPbI3 and also form a coordinative bond that stabilized cubic CsPbI₃ through the acylamino group (N-C=O). PVP was coordinatively bound to the surface of CsPbI₃ crystals (Figure 3b) [55]. Another example was shown by Fairfield et al. [49], who investigated the effect of polymer additives such as polyethylene glycol (PEG), polyethyleneimine (PEI), poly(acrylic acid) (PAA), and polyvinylpyrrolidone (PVP) on the crystal sizes and stability of perovskite-polymer hybrid films in humid air. Under humid air and illumination, it was discovered that perovskite–PAA hybrid solar cells retained a stable efficiency for the first three days and then gradually degraded over the next six days, while control perovskite solar cells degraded completely within the first two days (Figure 3c).

Polymer additives were used to extend the lifetime of perovskite. When these polymers were used, major improvements in perovskite dense films based on acid-base interaction were observed, as well as improved system stability under humid and illuminated conditions. There are many materials that were used as additives or passivation layers such as 3-aminopropyltrimethoxysilane [56], trichloro(octyl) silane [57], methoxysilane [58], poly (vinylidene fluoride-co-hexa-fluoropropylene) [59], polyamide [60], poly (styrene-co-acrylonitrile) polymer [61], polyvinyl butyral (PVB) [62], polyhedral oligomeric silsesquioxane-poly(trifluoroethyl methacrylate)-b-poly(methyl methacrylate) polymer [63], and both NbCl₅ and n-butylammonium bromide [64] in perovskite solar cells.

Apart from low-molecular-weight materials, Li et al. [65] reported the modification of the methylammonium lead triiodide (CH₃NH₃PbI₃) perovskite surface using a one-step spin coating method in the presence of 4-ABPACl. The benefit of using bifunctional 4-ABPACl molecules as additives is an increased moisture resistance by chemically anchoring ammonium (-NH₃⁺) cations, and phosphonic acids (-PO(OH)₂) and groups of the polymer to the perovskite grain surface through strong hydrogen bonding, that result in a photovoltaic performance from 8.8% to 16.7%. Also, 2-AET can be used as an additive and connect MAI and PbI₂ by a hydrogen bond between 2-AET and MAPbI₃. Additionally, Li et al. verified the stability of the mixed ligand-perovskite film by immersing it in water. The mixed film remained dark brown compared to pristine films, which was proven to the stability in the water. After DMF was removed, the thiolate groups of the ligand material may exhibit a stronger affinity for PbI₂, while the -NH₃⁺ group may exhibit affinity for MAI, forming PbI₂-2-AET- MAI [66].

Polymeric additive (large molecules)



 $\Phi_x = \Phi_{std} (Grad_x/Grad_{std}) (\eta_x^2/\eta_{std}^2)$ (6)

where Φ is the quantum yield of photoluminescence, *Grad* is the gradient of the linear plot of integrated fluorescence intensity vs. absorbance, *n* is the reflective index of solvent, and the subscripts "x" and "std" denote the test sample and fluorescent standard, respectively [73].

Colloidal perovskite QDs have rapidly emerged as a new class of extraordinary nanocrystal semiconductors and have been extensively investigated for applications in other technical fields. Due to their superior photoluminescence efficiency, lead halide perovskite QDs are nearly as bright and narrow as those based on cadmium chalcogenide. The reasons for the varied perovskite compositions have been discussed in previous reviews for solar cells [74] and scintillators [75]. From CdTe-based polycrystalline solar cells, it is known that CdS nanocrystals are applied as the p-n junction with CdTe absorbers to increase the PCE

3.3.2. Quantum dot (QD) additives

properties. Quantum dots (QDs) are semiconductor nanocrystals with tunable band gaps due to the quantum confinement effect, which have higher absorption coefficients than commonly used organic dyes, and multiple exciton generation [67, 68]. Over the last decade, QDs derived from II/VI and III/V semiconductors have matured into a new class of fluorescent markers for bioimaging probes, sensing, light-emitting, and optoelectronic applications. For example, colloidal quantum dots (CQDs) are favored due to their high photo- and thermal-stability in quantum dot solar cells [69, 70]. Quantum confinement offers an intriguing possibility for bandgap engineering. When particles are shrunk to less than their Bohr radius, the electron and hole wave functions are confined. Due to the wide bandgap, the optical transition exhibits a blue shift [71]. The quantum yield of photoluminescence or fluorescent quantum yield (Φ) is a critical performance indicator for determining the efficiency of QD fluorophores. Quantum yield values for photoluminescence represent the

Table 2. Polymeric additive	s for perovskite	modifications.
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Туре	Material	Molecular weight (g/mol)	Perovskite precursor	Step- deposition	Structure	PCE (%)	Testing condition: relative humidity and device stability	Ref.
Large-molecular	PDMS-Urea	850, 2500, 5000	MAPbI ₃	One-step	n-i-p	16.15	In dark with 50%RH, PDMS–urea (20 mg/ml) no degradation within 2500 h.	[53]
	PMMA	-	(FAI) _{0.81} (PbI2) _{0.85} (MAPbBr3) _{0.1}	One-step	n-i-p	21.00	3.3% decay in PCE during exposure to ambient air for two months in the dark.	[52]
	PEG,	-	MAPbI ₃	One-step	p-i-n	16.00	Unsealed, 48% RH, retained initial	[<mark>49</mark>]
	PEI,						PCE for 72 h.	
	PAA,							
	PVP							
PEG	PEG	12,000,	MAPbI ₃	One-step	n-i-p	16.00	-	[53]
		20,000,						
		100,000						
	PVP	10,000	*CsPbI ₃	One-step	n-i-p	10.70	Under continuous light (10 h under 70 mW/cm ²) illumination, moisture for over 300 h.	[55]
Small-molecular	2-AET	77.15	MAPbI ₃	One-and two-step	-	-	-	[<mark>66</mark>]
	4-ABPACI	153.12	MAPbI ₃	One-step	n-i-p	16.70	In ambient air at ~55% RH in the dark, currently recorded at 10% illumination intensity, PCEremainsat 14% for about a week.	[65]
* Cesium lead	iodides (CsPb	I3), %Relative hum	idity (%RH).					

owing to bandgap grading when S diffuses into the absorber material and thus extends the optical absorbance to shorter wavelengths due to CdTe_{1-x}S_x structures [3, 76]. In the following section, we will summarize and analyze the advantages of QDs in perovskite solar cells. MAPbBr₃, MAPbl_{3-x}Cl_x or CsPbBr₃ QDs can be used embedded in bulk materials, as nanoparticles, or in form of nanoplates for perovskite polycrystalline thin films for solar cells [77] or light-emitting diodes (LEDs) [78, 79, 80, 81, 82] because of their high stability, facile structural, and photophysical tunability [83]. These QD types are typically referred to as perovskite QDs. Another colloidal form of these nanocrystals is chalcogenide QDs (e.g., CdS, CdSe, or CdTe) or lead halide QDs (PbS or MPbX). The latter OD type was applied to create COD solar cells with a PCE of up to 10.6% [84]. Halide QDs can also be used for infrared-sensitive absorber materials and are therefore of interest in tandem solar cells [85]. Following the classification of solar cells by the National Renewable Energy Laboratory (NREL) [9], it must be highlighted that PbBr3-like crystal structures are allocated to 'perovskite solar cells', while chalcogenide or halide CQDs are assigned to so-called 'quantum dot solar cells'.

Numerous recent studies demonstrated that QDs can be used to enhance the photon resistance stability and efficacy of hybrid organicinorganic perovskites through effective charge separation following incident light absorption. Figure 4 shows the relationship between international publications collected and PCE of perovskite solar cells where QD materials have been integrated. The PCE increased from 3% [86] up to over 20% [87] in the period of 2014–2020. Thus, QDs are promising materials, which can be used to increase efficiency and commercialize perovskite solar cells.

QDs enhance the long-term photostability of perovskite photovoltaic devices (Table 3). The primary drawbacks of perovskite materials are their rapid degradation by moisture, their sensitivity toward UV light, and their electron-hole recombination. Thus, we emphasize the beneficial effect of QDs by stating that (i) some QDs were inserted between perovskite and TiO₂ layers, which can help to reduce the photocatalytic effect of TiO₂ that can damage the photoactive films [88], (ii) the most important QD species were passivated at the surface trap site of semiconductors, which prevented the formation of recombination pathways [89, 90], and (iii) most importantly, the introduction of QDs in

perovskite material, which can enhance material persistence around the VIS-NIR region due to light-induced degradation [91].

Over the last decade, CQDs have been synthesized as nanometer-scale semiconductor crystals capped with surfactant molecules and dispersed uniformly in solution. Controllability of the size and shape of QDs is important for tuning the quantum confinement effect, and optical and electrical properties, according to solution processing. All OD materials have shown exceptional efficiency in a wide variety of optoelectronic system groups. Generally, QD synthesis starts from small crystals that grow until the reaction is stopped. Two synthesis strategies that allow the controlled growth of QDs are widely used as illustrated in Figure 5. The in-situ process, which includes successive ionic layer adsorption and reaction (SILAR) and chemical bath deposition (CBD) [95], requires the growth direction of the QD self-assembly onto mesoporous substrates (e.g., metal oxide films). These reactions take place on electrode surfaces in the presence of a reactant precursor solution. For solar cell applications, ample QDs can be loaded into preferred metal oxide films (e.g., TiO₂ and ZnO) to allow for light harvesting while maintaining ease of preparation, and chemical stability [96, 97]. The QD-modified electrodes have a significant amount of sunlight harvesters and photoelectric conversion ability. Another ex-situ method is to prepare QDs by one-pot hydrothermal synthesis at temperatures between ca. 100-350 °C prior to their deposition on surface films with a known amount of QDs. Direct adsorption, electrophoretic deposition, and linker-assisted immobilization are the most frequently used methods for immobilizing the as-synthesized QDs on metal oxide semiconductor substrates. For the inand ex-situ deposition designs that have been discussed previously [98, 99, 100].

We survey the synthesized QD routes in order to obtain high-quality QDs dispersed solid materials with ideal bandgap absorption and dispersion properties. The one-pot hydrothermal method is commonly used to provide colloidal QD nanocrystals with nano-size between 5-10 nm. The primary determinants of the size and shape of QD nucleation are temperature and supersaturation concentrations in solution [101, 102]. Surfactants or capping ligands are contained in the precursor solutions during synthesis to ensure that colloidal QDs have a high surface-to-volume ratio and increase colloidal stability and thus



Figure 3. a) Schematic and SEM Image of perovskite surface without and with PEG via spin coating method (reproduced with permission [53], copyright 2016, Nature Communication); b) Chemical formation mechanism of PVP-induced cubic phase CsPbI₃ (reproduced with permission [55], copyright 2018, Nature Communication); and c) Stability of perovskite solar cell without and with PAA under 43% relative humidity in the air with illumination (reproduced with permission [49], copyright 2019, The Royal Society of Chemistry).

(c)

4

2

1

3

5

Time (days)

6

7

8

dispersibility. Typically, capping ligands have a polar head and a long hydrocarbon tail, such as trioctylphosphine oxide (TOPO), oleylamine, oleic acid (OA), 2-mercaptoethylamine (MA), and 1-octadecence (ODE). These ligands are chosen based on the Lewis values of acids and bases describing their reactivity in the precursor solution to coordinate chemistry with the QD surface atoms.

2

0

Numerous earlier studies have shown the use of various organic ligands such as fatty acids, long-chain amines, and phosphine acid groups as suitable ligands for controlling the structures and surface coordination of QDs. To obtain QDs with a narrow band distribution and shape, it is critical to select the appropriate ligands. For example, colloidal lead (Pb)and cadmium (Cd)- chalcogenide QDs were synthesized in a hot-injection process under N₂/Ar conditions using PbO and/or CdO capped with oleic acid (Ol⁻. H⁺). This process resulted in the formation of Pb/Cd oleate, more precisely Pb/Ol and Cd-Ol quantum dots [103, 104]. Afterward, the respective reaction flask was rapidly filled with sulfur (S) and/or tellurium (Te) precursors to form the completed CQDs. Trioctylphosphine (TOP) and trioctylphosphine oxide (TOPO) ligand molecules capped CdSe are primarily used for overcoating Cd atoms in a wet-chemical CdSe synthesis, as they have stronger capping properties than oleic acid [104, 105, 106, 107]. Due to their superior properties, colloidal QDs are promising materials for photovoltaics, light-emitting diodes, bioimaging, and drug delivery among other applications [108, 110, 111]. However, the instability of as-synthesized QDs is an obstacle to their further implementations and could result from the substitution of the ligands responsible for the instability. The modification of the surface of QDs by ligand exchange reaction can be done in solid-phase and solution-phase. Examples of ligand exchange are the replacement of pristine ligands (e.g., TOPO) with pyridine [104, 112]. Knauf et al. investigated the exchange of oleate-capped CdSe with phosphonic acids and thiols [113]. Reinhart and Johansson, compared the optical properties of as-synthesized 3-mer-captopropionic acid (3-MPA) capped PbS QDs to those of oleate-capped QDs [114].

3.3.2.2. Applications of quantum dots in perovskite solar cells. As illustrated in Table 4, we summarized different types of QDs for ETL,



Figure 4. Improvement of QDs based perovskite solar cells as a function of the percentage power conversion efficiency (PCE%). Evaluated international journal articles that were published by The Royal Society of Chemistry, American Chemical Society, Nature Publishing Group, The Wiley Online Library, and Elsevier, *etc.*, were searched by using the phrase "Quantum Dots for Perovskite Photovoltaic Devices".

Table 3. Sur	nmary of the per	entage degradation	n of perovskite so	olar cells (PS	Cs) with v	arious ODs.

Perovskite solar cells	Time (h)	Initial-final efficiency (%)	Device degradation (%)	Ref.
PSCs PSCs–CdS QDs	12	10.2-4.3 9.9-7.6	58.0 23.0	[89]
PSCs PSCs-Carbon QDs	12	1.0-0.2 1.0-0.7	80.0 30.0	[91]
PCBM PCBM-CdSe QDs	70	11.2–7.0 13.7–10.5	37.5 23.4	[92]
CsPbI ₃ CsPbI ₃ –Mn QDs	100	1.0-0.85 1.0-0.98	15.0 2.0	[93]
PSCs PSCs–PbS QDs	97	1.0–0.3 1.0–0.8	70.0 20.0	[88]
PSCs PSCs-Graphene QDs	720	8.5–1.0 14.5–13.5	90.0 10.0	[90]
PSCs PSCs–CsPbBrCl ₂ QDs	500	1.0–0.3 1.0–0.8	70.0 20.0	[94]

Designs of QD Synthesis Methods.

perovskite, and HTL layers in perovskite solar cells, demonstrating the parameters, namely a short current density (J_{sc}), an open-circuit voltage (V_{oc}), a fill factor (FF), and a percentage of power conversion efficiencies (PCE), for several cell compositions (measured at 1 sun-AM1.5G). Following sections will address QDs as an active layer in perovskite precursors, as well as HTLs and ETLs.

3.3.2.3. Quantum dots in perovskite layer. In general, the efficient performance strongly depends on the quality of perovskite active layers, such as their morphology, crystallinity, and composition. Therefore, a good crystal-forming process of the perovskite films, with high surface

coverage and minimum pinholes, is the most important factor that impacts the device performance. In turn, the main challenges to produce high-quality films are to control the crystal growth behavior, which depends on different factors such as the perovskite precursors, the deposition methods, the solvents, and the additives used [115, 116, 117, 118].

Some authors indicate that the instability of perovskite solar cells has not been resolved yet [119, 120]. Different QD types were used to produce QD perovskite solar cells. For example, cesium lead bromide QDs (CsPbBr₃) composited with mesoporous TiO₂ films have been synthesized and used to enhance electron transfer in photodetectors [121, 122]. In addition, the materials were also used to produce light-emitting diodes



Figure 5. Possible designs (left) of QD one-pot hydrothermal synthesis of chalcogenic CdTe, CdSe, or CdS with short-chain linker molecules (e.g., N-acetyl-L-cysteine, NAC), which can be exchanged for other linker molecules of interest using thiol chemistry (SH bonding with the QDs of e.g. trioctylphosphine oxide, TOPO), and schematic design of QD-deposited on substrates (right).

(LEDs) [123, 124, 125] and lasers [126, 127]. Swarnkar et al. demonstrated that by synthesizing cesium lead iodide (CsPbI₃) QDs at temperatures ranging from 60 °C to 185 °C, they were able to monitor the QD size range of 3.4–12.5 nm, which corresponded to the shifted excitonic peaks of CsPbI₃ between 585 and 670 nm. Their ultraviolet (UV) emissions ranged from orange (585 nm) to red (670 nm), indicating an energy band difference of 2.07 to 1.82 eV. Laboratory scale perovskite devices demonstrated high efficiency of 10.77%, for which QDs in the size of 9 nm (synthesized at a temperature of 180 °C) were used [128]. Cha et al. proposed the fabrication of hybrid planar perovskite solar cells using synthesized MAPbBr_{3-x}I_x (MA = CH₃NH₃) QDs by varying the Br to I ratio. Their modified QDs (with an average diameter of 5 nm) were used as interface phases between the perovskite film and HTL; the best cell achieved a considerable PCE of 13.32% [129].

The concentration of tin sulfide (SnS) quantum dots (QDs) in methylammonium lead iodide (MAPbI₃) precursor solution was varied to improve carrier separation and transportation. The MAPbI₃/SnS QD hybrid structure can also be used as an absorber layer due to its PCE of 16.8%. Before centrifugation, a particle size of 3 and 6 nm of SnS QDs was determined [130]. The superior crystallization of hybrid perovskite films reveals a large grain size, which results in a PCE of up to 18.6% when lead sulfide (PbS) QDs are added to the MAPbI₃ precursor [131]. Also, graphene QDs were used during the perovskite solution process to overcome the grain boundaries effect of perovskite crystals on PSC performance by passivation. As a result, a PCE of 17.62% could be achieved [132]. Especially, some types of QDs with different functional groups and an efficient processing method exhibit outstanding long-term humidity stability. Liu et al. [133] demonstrated chlorine-terminated Ti₃C₂ quantum dots (Ti₃C₂Cl_x QDs) as additives in perovskite precursor. The advantageous properties of the Cl-group in Ti₃C₂Cl_x QDs can form a strong bond with Pb²⁺ ions from the perovskite composition. In comparison to the hydroxyl (-OH) group in Ti₃C₂OH_x QDs, the perovskite solar cells could degrade significantly due to the Lewis acid-base reaction between -OH and organic amine groups in perovskite. This work showed that Ti₃C₂Cl_x QDs in devices without encapsulation maintained the PCEs greater than 84% for aging 1000 h under humidity testing in dark conditions [133].

3.3.2.4. Quantum dots in the hole-transporting layer (HTL). Several studies have shown that both organic and metallic QDs are also applicable for the HTL layer of perovskite solar cells: For example, so-called carbon QDs, which have a quantum-sized graphite structure and are an eco-friendly alternative to metal-based QDs [134], can be used as HTL materials to fabricate perovskite devices with documented efficiencies of 3% [85]. To minimize the defects in perovskite films, also graphene quantum dots (GQDs) were introduced into the perovskite films. This resulted in a smooth surface without pinholes, excellent conductivity, and light absorption, superior charge extraction, and a smaller leakage of current [135]. Regarding heavy metal-based QDs, Hu et al. reported a PCE of 7.5% for planar heterojunction perovskite solar cells using PbS colloidal quantum dots (average size 3 nm) as hole-transporters [136]. Rao et al. found a PCE of inverting planar heterojunction perovskite solar cells over 16% using CuS nanoparticles modified on the surface of indium tin oxide as hole-selective contacts [137]. CuInS2 QDs as inorganic hole

Type of QDs	Size (nm)	Cell architecture	Area (cm ²)	J _{sc} (mA/cm ²)	V _{oc} (V)	FF	PEC (%)	Ref.
QDs in Active Layer								
CsPbI ₃	-	FTO/TiO ₂ /CsPbI ₃ /spiro-OMeTAD/MoO _x /Al	0.10	13.47	1.23	0.65	10.77	[128
MAPbBr _{0.9} I _{2.1}	-	FTO/TiO ₂ /MAPbI ₃ /MAPbBr _{0.9} I _{2.1} QDs/spiro-OMeTAD/Au	-	19.51	0.95	0.72	13.32	[129
MAPbI ₃ : SnS	-	FTO/TiO2/MAPI (with SnS QDs)/spiro-OMeTAD/Au	-	22.70	1.04	0.72	16.80	[130
CsPbCl ₃ : Mn	~8	FTO/TiO ₂ /CsPbI ₃ : Mn QDs/spiro-OMeTAD/Au	-	22.03	1.11	0.76	18.57	[<mark>93</mark>]
MAPbI ₃ : Graphene	~3	FTO/TiO ₂ /MAPbI ₃ (with graphene QDs)/spiro-OMeTAD/Au	-	23.86	1.13	0.70	18.90	[135
MAPbI ₃ : PbS	4	FTO/TiO ₂ /MAPbI ₃ (with PbS QDs)/spiro-OMeTAD/Au	-	23.50	1.03	0.77	18.60	[131
MAPbI ₃ : Graphene	-	FTO/TiO ₂ /MAPbI ₃ -GQDs/spiro-OMeTAD/Au	0.09	22.49	1.03	0.76	17.62	[132
QDs in HTL								
Black phosphorus	5.2	ITO/PEDOT: PSS-BPQDs/MAPbI ₃ /PCBM/Ag	-	20.56	1.01	0.80	16.69	[139
Black phosphorus	3–10	ITO/BP QDs/FA _{0.85} MA _{0.15} PbBr _{0.5} I _{2.5} /spiro-OMeTAD/Au	0.09	16.77	1.03	0.65	11.26	[140
Carbon	-	FTO/TiO ₂ /mp-TiO ₂ /MAPbI ₃ /Carbon QDs/Au	-	7.83	0.52	0.74	3.00	[<mark>86</mark>]
CuInS ₂	-	FTO/TiO ₂ /CH ₃ NH ₃ PbI ₃ /CuInS ₂ /ZnS/Au	-	18.60	0.92	0.49	8.38	[138
PbS	-	FTO/TiO ₂ /MAPbI ₃ -PbS QDs/Au	0.12	24.63	0.34	0.43	3.60	[141
PbS	-	ITO/ZnO/MAPbI ₃ -PbS/PbS/Au	-	21.80	0.61	0.68	8.95	[142
PbS colloidal	-	ITO/PbS CQDs/CH ₃ NH ₃ PbI ₃ /PCBM/Al	-	12.10	0.86	0.72	7.50	[136
CuS	-	ITO/CuS/CH ₃ NH ₃ PbI ₃ /C60/BCP/Ag	0.10	22.30	1.02	0.71	16.00	[137
CuInS ₂	-	ITO/CuInS ₂ /Al ₂ O ₃ /CH ₃ NH ₃ PbI ₃ : CdS/PC ₆₀ BM/Ag	0.04	23.80	0.95	0.73	16.50	[156
CdSe	2–4	FTO/TiO ₂ /CH ₃ NH ₃ PbI ₃ /CdSe/spiro-OMeTAD/Au	-	20.40	-	-	17.00	[155
Cu ₂ ZnSnS ₄	~10	FTO/TiO ₂ /CH ₃ NH ₃ PbI ₃ /Cu ₂ ZnSnS ₄ /Au	0.15	18.75	0.95	0.61	10.72	[157
Cu ₂ ZnSnSe ₄	~10	FTO/TiO ₂ /CH ₃ NH ₃ PbI ₃ /Cu ₂ ZnSnSe ₄ /Au	0.15	19.37	0.81	0.62	9.72	[157
PbS	3.6	FTO/TiO ₂ /CH ₃ NH ₃ PbI ₃ /PbS/spiro-OMeTAD/Au	0.09	18.69	0.87	0.49	7.88	[143
QDs in ETL								
PbS	~5	FTO/TiO ₂ /PbS/MAPbI ₃ /P3HT/Pt	0.10	6.30	0.88	0.49	4.92	[<mark>88</mark>]
CdS	-	FTO/TiO2–CdS/MAPbI3/spiro-OMeTAD/Au	0.10	18.00	0.91	0.67	9.90	[<mark>89</mark>]
Carbon	~10	ITO/TiO ₂ (with Carbon QDs)/MAPbI _{3-x} Cl _x /spiro-OMeTAD/Au	-	21.36	1.14	0.78	18.90	[158
CdS	-	FTO/TiO ₂ /CdS/MAPbI ₃ /spiro-OMeTAD/Au	-	17.54	0.98	0.71	12.20	[147
Graphene	~5	ITO/PCBM (with GQDs)/MAPbI ₃ /spiro-OMeTAD/Au	0.40	22.03	1.09	0.73	17.56	[153
Graphene	5	FTO/ZnO (with GQDs)/CH ₃ NH ₃ PbI ₃ /spiro-OMeTAD/Au	0.15	21.70	1.03	0.68	15.20	[<mark>90</mark>]
CdSe	~10	ITO/PEDOT: PSS/CH ₃ NH ₃ PbI _{3-x} Cl _x /PCBM (with CdSe)/Rhodamine101/LiF/Ag	0.11	20.96	0.90	0.73	13.73	[<mark>92</mark>]
Carbon dots	~4.8	$\rm FTO/TiO_2$ (with Carbon dots)/MAPbCl_xI_{3-x}/spiro-OMeTAD/Au	-	22.64	1.02	0.72	16.40	[<mark>91</mark>]
Carbon dots	-	FTO/TiO ₂ /Carbon QDs/MAPbI ₃ /Carbon	0.14	16.40	0.79	0.61	7.62	[154
Graphene	~4	FTO/ZnO-Graphene/CH ₃ NH ₃ PbI ₃ /spiro-OMeTAD/Au	-	22.80	1.05	0.72	17.20	[<mark>90</mark>]
CdS nanorods	-	ITO/CdS NRs array/perovskite/spiro-OMeTAD/MoO ₃ /Ag	0.05	18.77	0.93	0.50	8.36	[146
Graphene	-	FTO/TiO ₂ /GQDs/CH ₃ NH ₃ PbI ₃ /spiro-OMeTAD/Au	0.13	17.06	0.94	0.64	10.15	[159
Zn ₂ SnO ₄	~5.7	$ITO/Zn_2SnO_4/MAPb(I_{0.9}Br_{0.1})_3/PTAA^*$	-	20.40	1.11	0.73	16.50	[149
ZnO	-	ITO-PET/Graphene/ZnO-QDs/CH3NH3PbI3/spiro-OMeTAD/Ag	-	16.80	0.94	0.62	9.73	[148
TiO ₂	3.6	FTO/TiO ₂ QDs/CH ₃ NH ₃ PbI ₃ /spiro-OMeTAD/Au	0.13	22.48	1.06	0.71	16.97	[160
Graphene	7–14	$\rm FTO/TiO_2$ (with GQDs)/CH_3NH_3PbI_3/spiro-OMeTAD/Au	0.11	22.47	1.12	0.62	9.73	[161
Graphene: SnO ₂	5–10	ITO/SnO ₂ (with GQDs)/CH ₃ NH ₃ PbI ₃ /spiro-OMeTAD/Au	0.10	23.05	1.13	0.78	20.31	[87]
γ-graphdiyne (GD)	3–5	FTO/TiO ₂ (with GD QDs)/CH ₃ NH ₃ PbI ₃ /spiro-OMeTAD/Au	0.09	22.48	1.12	0.79	19.89	[162

*Spiro-OMeTAD: 2,2',7,7'-tetrakis (N,N-di-pmethoxyphenyla- mine)-9,9'-spirobifluorene, BCP: Bathocuproine, PTAA: Poly[bis(4-phenyl) (2,4,6-trimethylphenyl)amine], PET: Polyethylene terephthalate.



Figure 6. Comparison of different power conversion efficiencies with each of QDs for the active layer, HTL, and ETL.

conductors for perovskite solar cells were investigated by Lv et al. Cation exchange modification of the surface of $CuInS_2$ QDs to form $CuInS_2/ZnS$ core/shell heterostructure QDs resulted in a PCE of 8.38% [138].

In the following section, we discuss organic materials composed of QDs, such as QD-convened organic polymers. Chen et al. used black phosphorus QDs (BPODs) deposited on poly(3,4ethylenedioxythiophene) polystyrene sulfonate (PEDOT:PSS) films on the anode side of pin planar hybrid perovskite solar cells with the following structure: ITO/PEDOT: PSS:BPQDs/MAPbI₃/PCBM/Ag. This experiment demonstrated that BPQDs deposited on polymer films significantly improve hole extraction and photon conversion efficiency in comparison to the reference system [139]. For complete flexible perovskite devices, BPQDs (diameter ranged from 3 to 10 nm) with a PCE of 11.26% were constructed as ETL on ITO/PEN (indium tin oxide coated on polyethylene-naphthalate) substrates [140]. Meanwhile, BPQDs had the ability to decrease the trap state in the perovskite film, resulting in improved crystallization and recombination losses. Apart from that, incorporating QDs into light-harvesting materials is one of the strategies for improving photovoltaic efficiency. Some studies reported that the fabrication of perovskite solar systems using PbS-QDs as HTL (both one-step and two-step methods were used) resulted in a decrease in charge recombination and a longer absorption peak in the visible and near-infrared (NIR) range [136, 141, 142, 143].

3.3.2.5. Quantum dots in electron transport layer (ETL). Using QDs as ETL is one technique to increase PSC performance. These solar cells require low-temperature solutions. Unlike perovskite layers, ETL is made of TiO_2 calcined at high temperatures. It is used in perovskite solar cells because it has high performance and low hysteresis but has metal-oxide preparation restrictions [144, 145]. Moreover, the photocatalytic activity of TiO_2 also limits visible light absorption and fast electron-hole recombination.

Many reports introduced QDs to the ETL layer, where an inorganic semiconductor was replaced with planar structures through a solution process using CdS [108]. The fabrication of planar photovoltaic devices based on CdS was successfully performed, with the best cell exceeding 15% in PCE [144] and 11.2% PCE under reverse scan conditions [145]. Gu et al. demonstrated the hydrothermally synthesized planar heterostructure hybrid perovskite solar cells used CdS nanorods (CdS NRs) arrays as an electron transporter. The devices configured as an ITO/CdS NRs array/perovskite/spiro-OMeTAD/MoO3/Ag array achieved the highest efficiency of 8.36% with an active area of 0.05 cm² after a 10-minute UV ozone treatment [146]. Hwang and Yong demonstrated that using CdS as a hole-blocking layer instead of the more conventional compact TiO₂ layer improved the photostability of perovskite solar cells. As a result, it was demonstrated that perovskite solar cells with the CdS layer exhibit significantly improved photostability, retaining over 90% of their initial efficiency after 12 h of sunlight illumination, while the TiO₂ perovskite solar cell retained only 18% of its initial efficiency under the same conditions [147]. Ameen et al. fabricated flexible perovskite devices with a 9.73% PCE using ZnO QDs deposited on flexible ITO-PET/graphene thin films through a spin coating approach [148]. With methylammonium lead halide [MAPb(I_{0.9}Br_{0.1})₃], zinc stannate (Zn₂SnO₄) particles with a size of 10 nm could achieve a PCE of 16.0% [149].

QD-sensitized solar cells are typically well-characterized QD-materials incorporated into a nanostructure semiconductor (e.g., TiO₂, ZnO) by one of three processes: electrodeposition, chemical bath deposition, or successive ionic layer adsorption and reaction (SILAR) [150]. Due to the fact that the hole-electron pairs were formed under illuminated conditions; their charge carriers combine at the semiconductor–QD interface. Recombination of charge carriers results in photocurrent failure, but also in the instability of the liquid electrolyte, lowering the efficiency of the solar cell. The primary advantage of QDs as sensitizers in the cell, however, is their tunable but size-dependent bandgap properties [98, 108, 109, 151]. Thus, in perovskite devices, QDs are deposited on the surface of the semiconductors or incorporated into a mesoporous TiO₂. PbS QDs (with a diameter of 5 nm) are deposited on crystalline TiO₂ photoanode films using the SILAR process as part of the QD-composed inorganic materials. The PbS QDs were observed to act as a NIR light absorber and a surface-blocking layer [88]. Following that, the addition of a CdS/TiO₂ electrode with a core/shell structure could improve the stability under illumination of perovskite solar cells. Additionally, the TiO₂/CdS core/shell structure was used as an electron transporter in perovskite photovoltaic cells to passivate surface trap sites on the TiO₂ layer [89].

The incorporation of carbon QDs (average diameter 4.8 nm) into a mesoporous TiO₂ layer can improve the electron transfer capability. PCE of 16.4% is possible [91, 112]. The synthesis of graphene quantum dots (with a variable size of 3-10 nm) was carried out using ZnO and TiO₂ layers [90, 152]. By using quick electron extraction, graphene quantum dots (GQDs) can be induced and improve the PCE up to 10%. Regarding organic materials composed of QDs as ETL, an optimized content of 5% CdSe/PCBM composite resulted in an acceptable PCE of 13.7% for inverted planar perovskite devices [92]. Yang also registered different graphene quantum dot concentrations in PCBM solutions using the fabricated structure ITO/PCBM/MAPbI3/spiro-OMeTAD/Au. A PCE of 17.5% was observed when 0.5%wt GQDs (with a size of 5 nm) were combined with PCBM solution [153]. Carbon QDs with different uniform diameters of 3-5 nm were introduced into perovskite films, and their effects on the performance of TiO2 nanosheet-based perovskite films resulted in a PCE of 7.62% [154].

To demonstrate the further value of QDs, Figure 6 compares the efficiency of perovskite solar cells with and without various forms of QDs as an active absorber (pink-bar section), an HTL (purple-bar section), and an ETL (blue-bar section). To improve the efficiency of perovskite devices, several different quantum dots were used. This graph depicts the low to high power conversion efficiencies in three parts, from left to right. It was observed that the function of QDs in the development of perovskite solar cells earned maximum efficiencies of 17.0% [155] 18.9% [92], and 20.3% [87] for CsPbCl₃: Mn (a photoactive absorber), CdSe (a hole collecting layer), and graphene: SnO₂ (an electron transporting layer), respectively, even though, the real active area of high-performance solar cells is still small (0.10 cm²).

4. Conclusions and outlook

The sensitivity of perovskite solar cells towards environmental factors is a major consideration and has to be addressed for becoming a commercial industrial technology. This review discusses the stabilization of perovskite solar cells, particularly against humid environments by using internal additive materials that passivate the surface by small linker molecules, polymers, or photo-stabilizing agents, such as quantum dots. This article discusses a variety of QD types used in conventional and inverted perovskite solar cells. QDs in perovskite solar cells allowed the improvement of the performance with recent power conversion efficiencies approaching 20%. QDs that were implemented in perovskite sheets, HTL, and ETL demonstrated an improvement in the efficiency of perovskite solar cells, which is summarized in this review. The implementation of QDs in perovskite cells resulted in the reduction of the recombination pathways, which in turn resulted in the long-term stability of perovskite devices.

Challenges, such as stability issues, necessitate additional research into processing routes toward improved product quality in order to advance perovskite technology. The back electrode (i.e., Au, and Ag) is mostly used for perovskite designs, but it is not suitable for pushing the perovskite photovoltaic market. Ag, which is the cheaper material, reacts with the halides, e.g., iodide from perovskite, and forms AgI, which results in a loss of the device performance, while Au electrode is mostly inert but far more expensive. In addition, transparent conducting oxide electrodes are necessary to replace metal-based materials, which would allow the evolvement of perovskite-based tandem solar cells. On the other hand, carbon materials as a top electrode are also applied for flexible perovskite solar cells due to excellent electric and optical, low cost, upscale fabrication technique, as well as improved perovskite lifetime. However, the International Summit on Organic Photovoltaic Stability (ISOS) protocols (i.e., dark storage (ISOS-D), light soaking (ISOS-L), etc.) [163] are required to examine the perovskite operational stability and real testing outdoor stability (ISOS–O) [163] to determine effects of weather on the perovskite modules, which is necessary for commercial application in near future.

An advantage of perovskite photovoltaic to succeed in the energy market is the manufacturing cost, which corresponds to the levelized cost of electricity (LCOE) of about 3.5–4.9 US cents/kWh, which is cheaper than traditional energy sources [164]. However, cost analysis of perovskite-silicon and perovskite-perovskite tandem modules were evaluated to be 5.22 and 4.22 US cents/kWh, respectively [165], which may become cheaper with the advances in electrode materials. Therefore, the future status of the perovskite photovoltaic field might be unveiled for the next-generation photovoltaic field.

Declarations

Author contribution statement

All authors listed have significantly contributed to the development and the writing of this article.

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Data availability statement

Data included in article/supplementary material/referenced in article.

Declaration of interests statement

The authors declare no conflict of interest.

Additional information

No additional information is available for this paper.

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